NSN 5961-01-359-9644

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-9644 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.130 inches and 0.200 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 660.0 breakdown voltage, dc and 600.0 working peak reverse voltage **Current Rating Per Characteristic:** 100.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Diode mtd in a connector plug; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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